

Schottky Barrier Rectifier

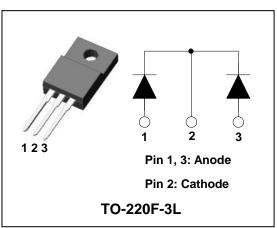
DUAL COMMON CATHODE SCHOTTKY RECTIFIER

Features

- Low forward voltage drop
- Low power loss and High efficiency
- Low leakage current
- High surge capability
- Full lead (Pb)-free and RoHS compliant device

Applications

- Switching power supplies
- Converter
- Free-wheeling diode
- Reverse battery protection
- Power inverters



Product Characteristics

I _{F(AV)}	2 X 8A
V _{RRM}	100V
V_{FM} at 125 $^\circ\!$	0.72V
I _{FSM}	180A

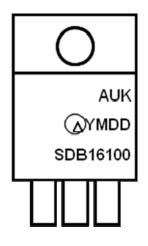
Description

The SDB16100PI Schottky rectifier has been optimized for low reverse leakage at high temperature. Ideally suited for use in low voltage, high frequency switching power supplies, free-wheeling diodes, and polarity protection diodes.

Ordering Information

Device	Marking Code	Package	Packaging
SDB16100PI SDB16100		TO-220F-3L	Tube

Marking Information



AUK = Manufacture Logo
Δ = Control Code of Manufacture
YMDD = Date Code Marking
. Y = Year Code
. M = Monthly Code
. D = Daily Code
SDB16100 = Specific Device Code

Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit	
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V _{RRM} V _{RWM} V _R	100	V	
Maximum average forward rectified current	per diode		8	A	
	total device	I _{F(AV)}	16		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I _{FSM}	180	А	
Storage temperature range		T _{stg}	-45℃ to +150℃	°C	
Maximum operating junction temperature		Tj	150	°C	

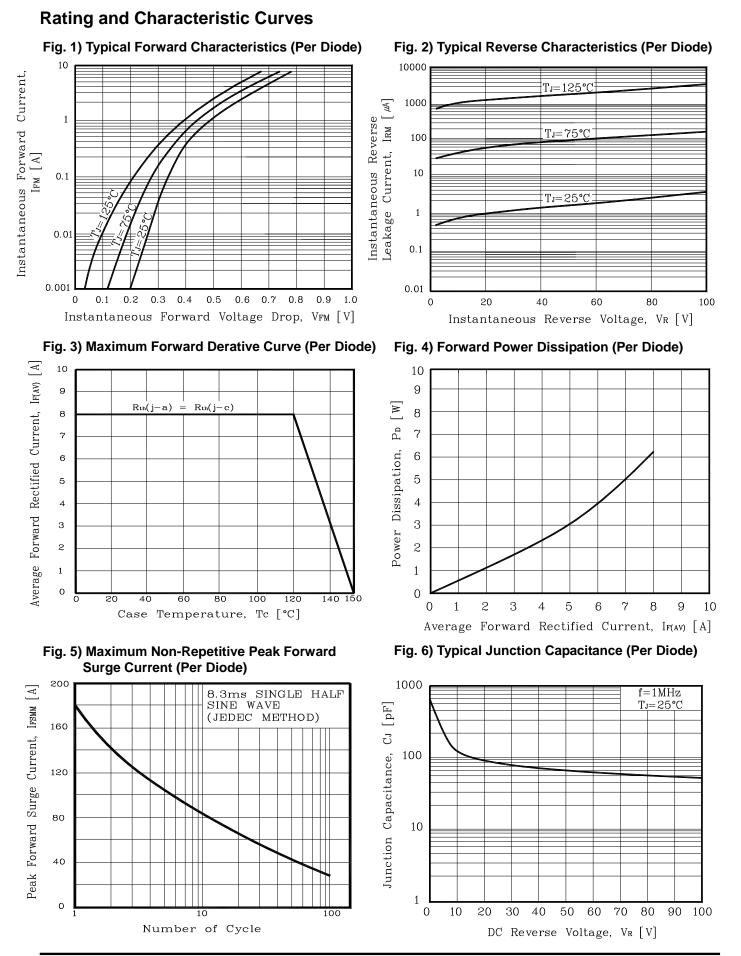
Thermal Characteristics

Characteristic		Symbol	Value	Unit
Maximum thermal registeries junction to eace	per diode	D	4.0	°C/W
Maximum thermal resistance junction to case	total device	R _{th(j-c)}	3.6	

Electrical Characteristics (Per Diode)

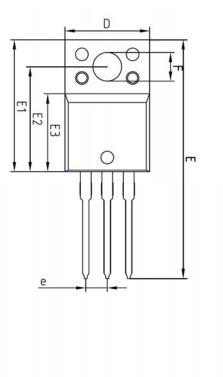
Characteristic	Symbol	Test Condition		Min.	Тур.	Max.	Unit
Peak forward voltage drop	${\sf V_{FM}}^{(1)}$	I _{FM} = 8A	T j =25 ℃	-	-	0.82	V
			Tj =125 ℃	-	-	0.72	V
Deverse lealers average	$I_{\rm RM}^{(1)}$	V _R = V _{RRM}	T j =25 ℃	-	-	0.1	mA
Reverse leakage current			Tj =125 ℃	-	-	5.0	mA
Junction capacitance	C _j	$V_R = 10V_{DC}$, f=1MHz		-	130	-	pF

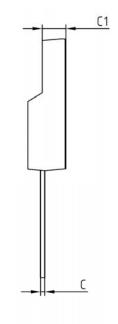
Note : (1) Pulse test : $t_{P}\!\leq\!380~\mu\!\!/\text{s},$ Duty cycle $\leq\!2\%$

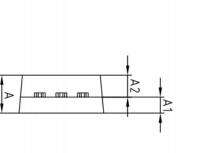


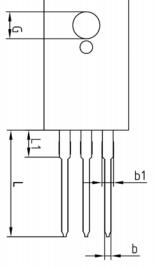
KSD-D00017-001

Package Outline Dimension









CYMPO	MILLIMETERS			NOTE
SYMBOL	MINIMUM	NOMINAL	MAXIMUM	NOTE
A	-	-	4.60	
A1	2.45	2.50	2.55	
A2	1.95	2.00	2.05	
b	0.65	0.75	0.85	
b1	1.07	1.27	1.47	
С	0.40	0.50	0.60	
C1	2.70	2.80	2.90	
D	9.90	10.00	10.10	
E	28.00	-	28.60	
E1	15.50	15.60	15.70	
E2	12.30	12.40	12.50	
E3	9.15	9.20	9.25	
F	3.30	3.40	3.50	
G	3.10	3.20	3.30	
е				
L	12.40	-	13.00	
L1				

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